

Lithium Niobate Crystal (LiNbO₃)

Introduction

LiNbO₃ Crystal is widely used as frequency doublers for wavelength >1μm and optical parametric oscillators (OPOs) pumped at 1064 nm as well as quasi-phase-matched (QPM) devices. Additionally due to its large Electro-Optic(E-O) and Acousto-Optic(A-O) coefficients, LiNbO₃ crystal is the most commonly used material for Pockel Cells, Q-switches and phase modulators, waveguide substrate, and surface acoustic wave(SAW) wafers, etc. **CASTECH** can provide LiNbO₃ crystals with high quality and large size for all these applications.

Structural and Physical Properties of LiNbO₃

Crystal Structure:	Trigonal, Space group R3c, Point group 3m
Cell Parameters:	a=5.148 Å , c=13.863 Å
Melting Point:	1253°C
Curie Temperature:	1140°C
Mohs Hardness:	5
Density:	4.64 g/cm ³
Elastic Stiffness Coefficients	C ^E ₁₁ =2.33(×10 ¹¹ N/m ²) C ^E ₃₃ =2.77(×10 ¹¹ N/m ²)

Optical and Electro-optical Properties of LiNbO₃

Transparency Range:	420-5200nm
Optical Homogeneity:	~ 5 x 10 ⁻⁵ /cm
Refractive Indices:	n _e = 2.146, n _o = 2.220 @ 1300 nm n _e = 2.156, n _o = 2.232 @ 1064 nm n _e = 2.203, n _o = 2.286 @ 632.8 nm
NLO Coefficients:	d ₃₃ = 86 x d ₃₆ (KDP) d ₃₁ = 11.6 x d ₃₆ (KDP) d ₂₂ = 5.6 x d ₃₆ (KDP)
Effective NLO Coefficients:	d _{eff} (I)=d ₃₁ sinθ-d ₂₂ cosθsin3φ d _{eff} (II)=d ₂₂ cos ² θcos3φ
Electro-Optic Coefficients	γ ^T ₃₃ = 32 pm/V, γ ^S ₃₃ = 31 pm/V, γ ^T ₃₁ = 10 pm/V, γ ^S ₃₁ = 8.6 pm/V, γ ^T ₂₂ = 6.8 pm/V, γ ^S ₂₂ = 3.4 pm/V,
Half-Wave Voltage, DC Electrical field // z, light ⊥ z: Electrical field // x or y, light // z:	3.03 KV 4.02 KV
Damage Threshold	100 MW/cm ² (10 ns, 1064nm)

Thermal and Electrical Properties of LiNbO₃

Melting Point:	1250°C
Curie Temperature:	1140°C
Thermal Conductivity:	38W/m/K @25°C
Thermal Expansion Coefficients (at 25°C):	//a, $2.0 \times 10^{-6}/K$ //c, $2.2 \times 10^{-6}/K$
Resistivity:	$2 \times 10^{-6} \Omega \cdot \text{cm}$ @200°C
Dielectric Constants:	$\epsilon_{11}^S/\epsilon_0 = 43$ $\epsilon_{11}^T/\epsilon_0 = 78$ $\epsilon_{33}^S/\epsilon_0 = 28$ $\epsilon_{33}^T/\epsilon_0 = 32$
Piezoelectric Strain Constant:	$D_{22} = 2.04 (\times 10^{-11} \text{C/N})$ $D_{33} = 19.22 (\times 10^{-11} \text{C/N})$

The Sellmeier equations (λ in μm) :

$$n_o^2 = 4.9048 + 0.11768 / (\lambda^2 - 0.04750) - 0.027169\lambda^2$$

$$n_c^2 = 4.5820 + 0.099169 / (\lambda^2 - 0.04443) - 0.02195\lambda^2$$

Specifications

- Transmitting wavefront distortion: less than $\lambda/4$ @ 633 nm
- Dimension tolerance: (W \pm 0.1 mm) x (H \pm 0.1 mm) x (L \pm 0.2mm)
- Clear aperture: > 90% central area
- Flatness: $\lambda/8$ @ 633 nm
- Scratch/Dig code: 20/10 to MIL-PRF-13830B
- Parallelism: better than 20 arc seconds
- Perpendicularity: 5 arc minutes
- Angle tolerance: $< \pm 0.5^\circ$
- AR coating: dual wave band AR coating at 1064/532 nm on both surfaces, with R < 0.2% at 1064nm and R < 0.5% at 532nm per surface.

Other coatings are available upon request.